

400V PNP HIGH VOLTAGE TRANSISTOR IN SOT223
Features

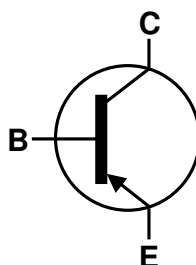
- $BV_{CEO} > -400V$
- $I_C = -500mA$ High Continuous Current
- $I_{CM} = 1A$ Peak Pulse Current
- Low Saturation Voltage $V_{CE(SAT)} < 250mV @ 50mA$
- $h_{FE} > 40$ Specified up to 200mA for High Current Gain Hold Up
- Complementary NPN Type: FZT658
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

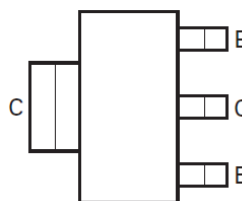
- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads;
- Solderable per MIL-STD-202, Method 208 
- Weight: 0.112 grams (Approximate)



Top View



Device Symbol


 Top View
 Pin-Out

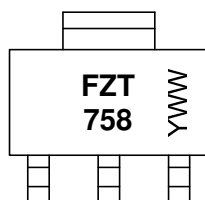
Ordering Information (Note 4)

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT758TA	FZT758	7	12	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information

SOT223



FZT 758 = Product Type Marking Code
 YWW = Date Code Marking
 Y or $\overline{Y}$ = Last Digit of Year (ex: 5= 2015)
 WW or $\overline{WW}$ = Week Code (01~53)

Absolute Maximum Ratings (@T_A = +25 °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-400	V
Collector-Emitter Voltage	V _{CEO}	-400	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-0.5	A
Peak Pulse Current	I _{CM}	-1	A

Thermal Characteristics (@T_A = +25 °C, unless otherwise specified.)

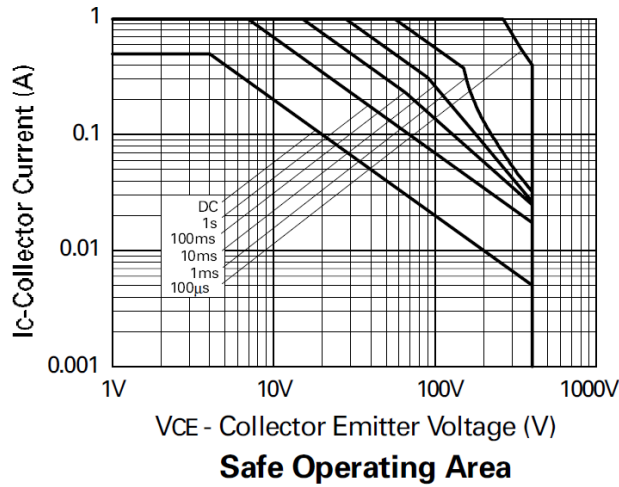
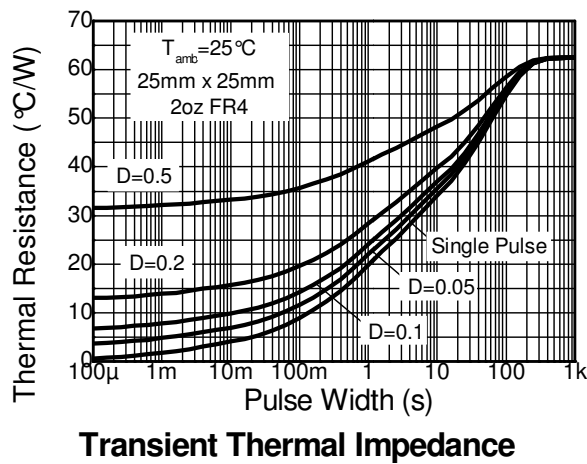
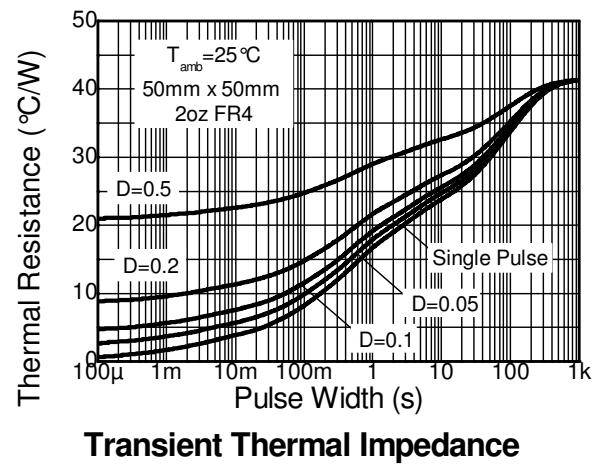
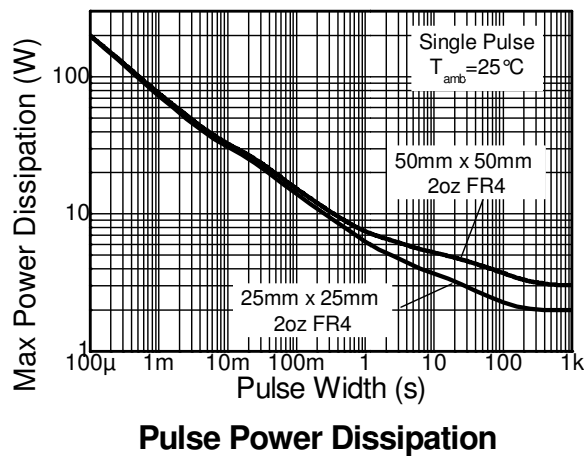
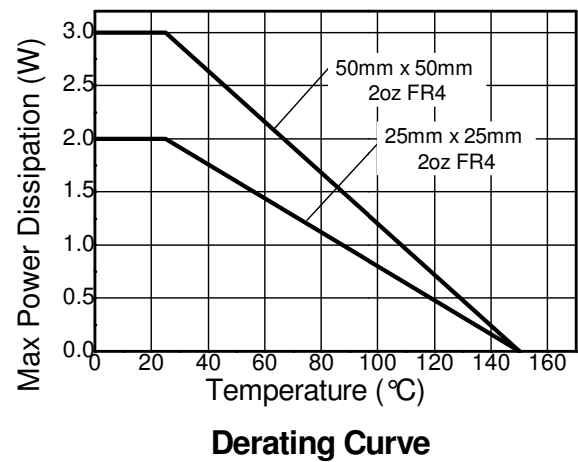
Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	3.0	W
		2.0	
		1.6	
		1.2	
Thermal Resistance, Junction to Ambient	R _{θJA}	41.7	°C/W
		62.5	
		78.1	
		104	
Thermal Resistance Junction to Lead	R _{θJL}	12.9	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 - Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
 - Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
 - Same as Note 5, except the device is mounted on minimum recommended pad layout.
 - Thermal resistance from junction to solder-point (at the end of the collector lead).
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

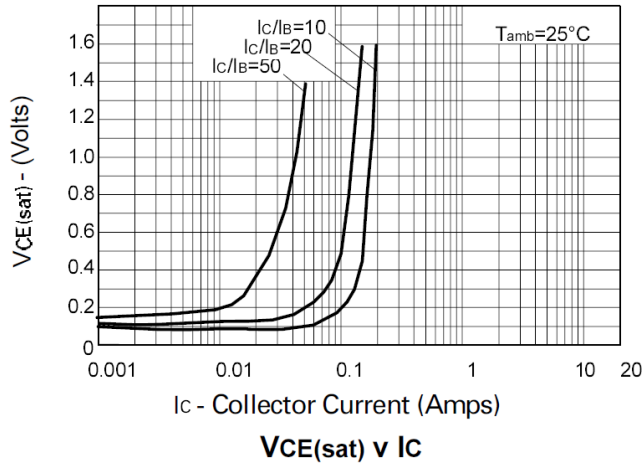
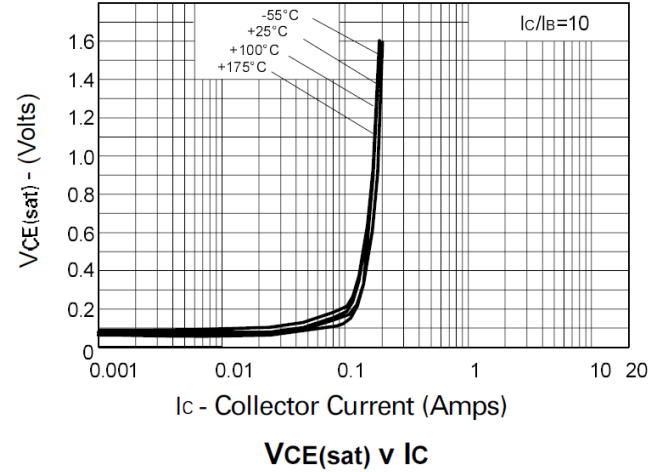
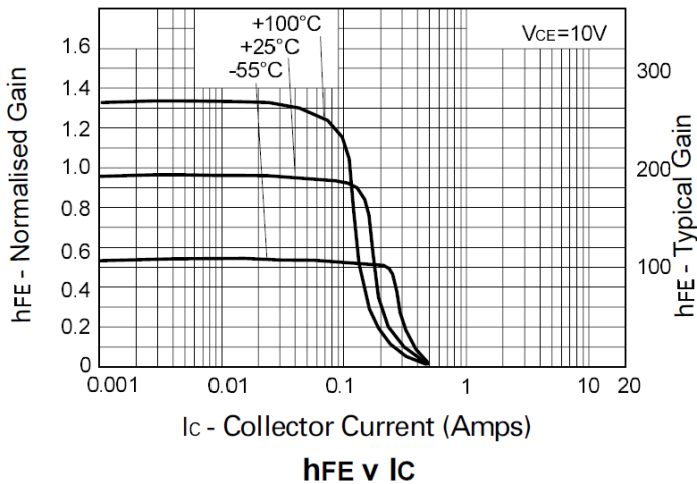
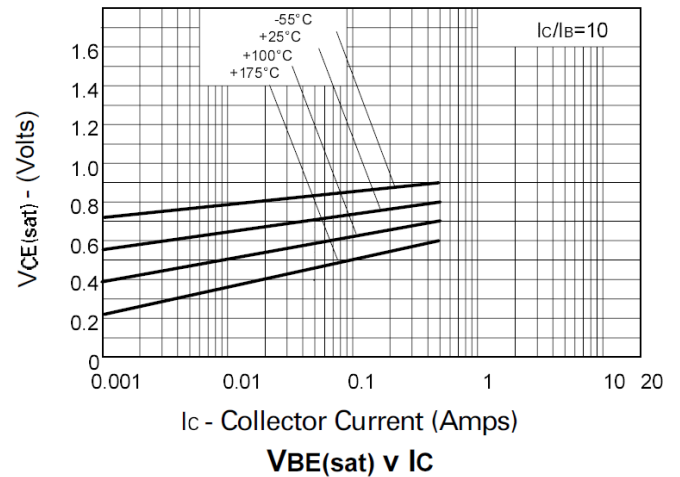
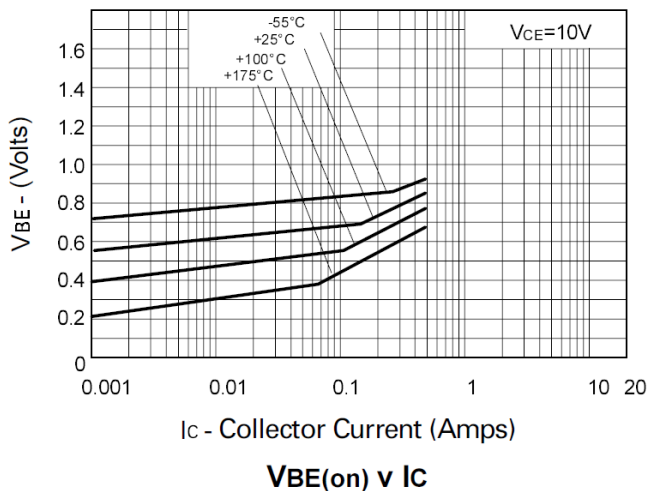


Electrical Characteristics (@T_A = +25 °C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-400	—	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	-400	—	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	—	—	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	—	—	-100	nA	V _{CB} = -320V
Collector Cut-Off Current	I _{CES}	—	—	-100	nA	V _{CE} = -320V
Emitter Cut-Off Current	I _{EBO}	—	—	-100	nA	V _{EB} = -4V
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}	—	—	-0.30	V	I _C = -20mA, I _B = -1mA
				-0.25		I _C = -50mA, I _B = -5mA
				-0.50		I _C = -100mA, I _B = -10mA
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	—	—	-0.9	V	I _C = -100mA, I _B = -10mA
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(on)}	—	—	-1.0	V	I _C = -100mA, V _{CE} = -5V
DC Current Gain (Note 11)	h _{FE}	50	—	—	—	I _C = -1mA, V _{CE} = -5V
		50	—	—		I _C = -100mA, V _{CE} = -5V
		40	—	—		I _C = -200mA, V _{CE} = -10V
Current Gain-Bandwidth Product (Note 11)	f _T	50	—	—	MHz	V _{CE} = -20V, I _C = -20mA, f = 20MHz
Output Capacitance (Note 11)	C _{obo}	—	—	20	pF	V _{CB} = -20V, f = 1MHz
Switching Times	t _{on}	—	140	—	ns	I _C = -100mA, V _{CC} = -100V I _{B1} = 10mA, I _{B2} = -20mA
	t _{off}	—	2,000	—		

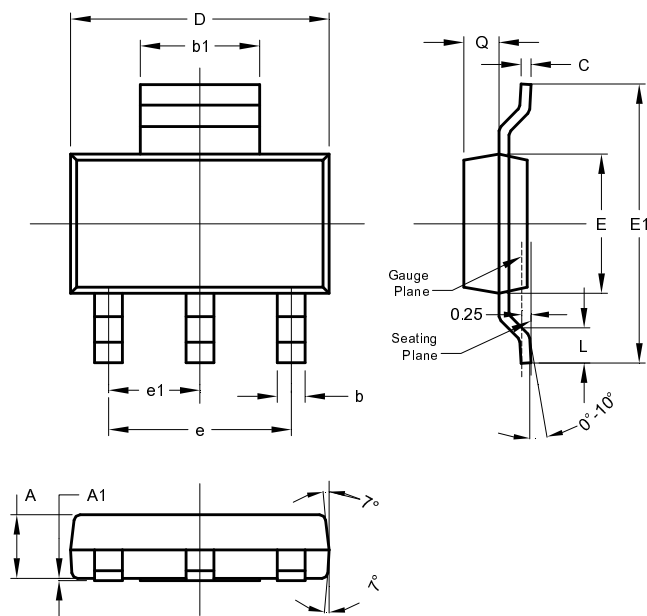
Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

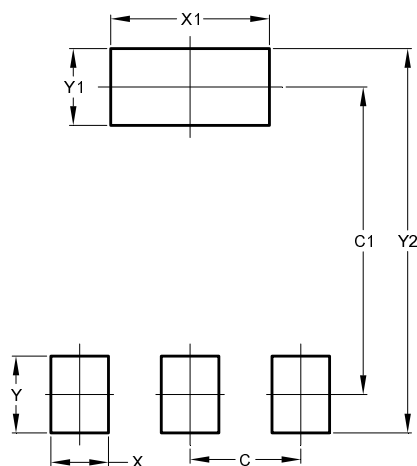


SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

SOT223



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.

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